

PDTC124TT,215 Datasheet



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DiGi Electronics Part Number	PDTC124TT,215-DG
Manufacturer	Nexperia USA Inc.
Manufacturer Product Number	PDTC124TT,215
Description	TRANS PREBIAS NPN 50V TO236AB
Detailed Description	Pre-Biased Bipolar Transistor (BJT) NPN - Pre-Biased 50 V 100 mA 250 mW Surface Mount TO-236AB



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Purchase and inquiry

Manufacturer Product Number:

PDTC124TT,215

Series:

-

Transistor Type:

NPN - Pre-Biased

Voltage - Collector Emitter Breakdown (Max):

50 V

DC Current Gain (hFE) (Min) @ Ic, Vce:

100 @ 1mA, 5V

Current - Collector Cutoff (Max):

1 μ A

Grade:

Automotive

Mounting Type:

Surface Mount

Supplier Device Package:

TO-236AB

Manufacturer:

Nexperia USA Inc.

Product Status:

Active

Current - Collector (Ic) (Max):

100 mA

Resistor - Base (R1):

22 kOhms

Vce Saturation (Max) @ Ib, Ic:

150mV @ 500 μ A, 10mA

Power - Max:

250 mW

Qualification:

AEC-Q100

Package / Case:

TO-236-3, SC-59, SOT-23-3

Base Product Number:

PDTC124

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0095

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

DISCRETE SEMICONDUCTORS

DATA SHEET

PDTC124T series

NPN resistor-equipped transistors;

R1 = 22 k Ω , R2 = open

Product data sheet
Supersedes data of 2004 Apr 06

2004 Aug 13

**NPN resistor-equipped transistors;
R1 = 22 kΩ, R2 = open**

PDTC124T series

FEATURES

- Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	–	50	V
I _O	output current (DC)	–	100	mA
R1	bias resistor	22	–	kΩ
R2	open	–	–	–

DESCRIPTION

NPN resistor-equipped transistor (see “Simplified outline, symbol and pinning” for package details).

PRODUCT OVERVIEW

TYPE NUMBER	PACKAGE		MARKING CODE	PNP COMPLEMENT
	PHILIPS	EIAJ		
PDTC124TE	SOT416	SC-75	41	PDTA124TE
PDTC124TEF	SOT490	SC-89	35	PDTA124TEF
PDTC124TK	SOT346	SC-59	50	PDTA124TK
PDTC124TM	SOT883	SC-101	DY	PDTA124TM
PDTC124TS	SOT54 (TO-92)	SC-43	TC124T	PDTA124TS
PDTC124TT	SOT23	–	*45 ⁽¹⁾	PDTA124TT
PDTC124TU	SOT323	SC-70	*50 ⁽¹⁾	PDTA124TU

Note

1. * = p: Made in Hong Kong.
* = t: Made in Malaysia.
* = W: Made in China.

NPN resistor-equipped transistors;
 R1 = 22 kΩ, R2 = open

PDTC124T series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PINNING	
		PIN	DESCRIPTION
PDTC124TS	<p style="text-align: center;"><i>MAM361</i></p>	1 2 3	base collector emitter
PDTC124TE PDTC124TEF PDTC124TK PDTC124TT PDTC124TU	<p style="text-align: center;">Top view <i>MDB270</i></p>	1 2 3	base emitter collector
PDTC124TM	<p style="text-align: center;">Bottom view <i>MHC507</i></p>	1 2 3	base emitter collector

NPN resistor-equipped transistors;
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PDTTC124T series

ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
PDTTC124TE	–	plastic surface mounted package; 3 leads	SOT416
PDTTC124TEF	–	plastic surface mounted package; 3 leads	SOT490
PDTTC124TK	–	plastic surface mounted package; 3 leads	SOT346
PDTTC124TM	–	leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm	SOT883
PDTTC124TS	–	plastic single-ended leaded (through hole) package; 3 leads	SOT54
PDTTC124TT	–	plastic surface mounted package; 3 leads	SOT23
PDTTC124TU	–	plastic surface mounted package; 3 leads	SOT323

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	–	50	V
V _{CEO}	collector-emitter voltage	open base	–	50	V
V _{EBO}	emitter-base voltage	open collector	–	5	V
I _O	output current (DC)		–	100	mA
I _{CM}	peak collector current		–	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	SOT54	note 1	–	500	mW
	SOT23	note 1	–	250	mW
	SOT346	note 1	–	250	mW
	SOT323	note 1	–	200	mW
	SOT490	notes 1 and 2	–	250	mW
	SOT883	notes 2 and 3	–	250	mW
SOT416	note 1	–	150	mW	
T _{stg}	storage temperature		–65	+150	°C
T _j	junction temperature		–	150	°C
T _{amb}	operating ambient temperature		–65	+150	°C

Notes

1. Refer to standard mounting conditions.
2. Reflow soldering is the only recommended soldering method.
3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

NPN resistor-equipped transistors;
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PDTTC124T series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W
SOT416	note 1	833	K/W	

Notes

1. Refer to standard mounting conditions.
2. Reflow soldering is the only recommended soldering method.
3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A	–	–	100	nA
I _{CEO}	collector-emitter cut-off current	V _{CE} = 30 V; I _B = 0 A	–	–	1	μ A
		V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C	–	–	50	μ A
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A	–	–	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 1 mA	100	–	–	
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA	–	–	150	mV
R1	input resistor		15.4	22	28.6	k Ω
C _c	collector capacitance	I _E = i _e = 0 A; V _{CB} = 10 V; f = 1 MHz	–	–	2.5	pF

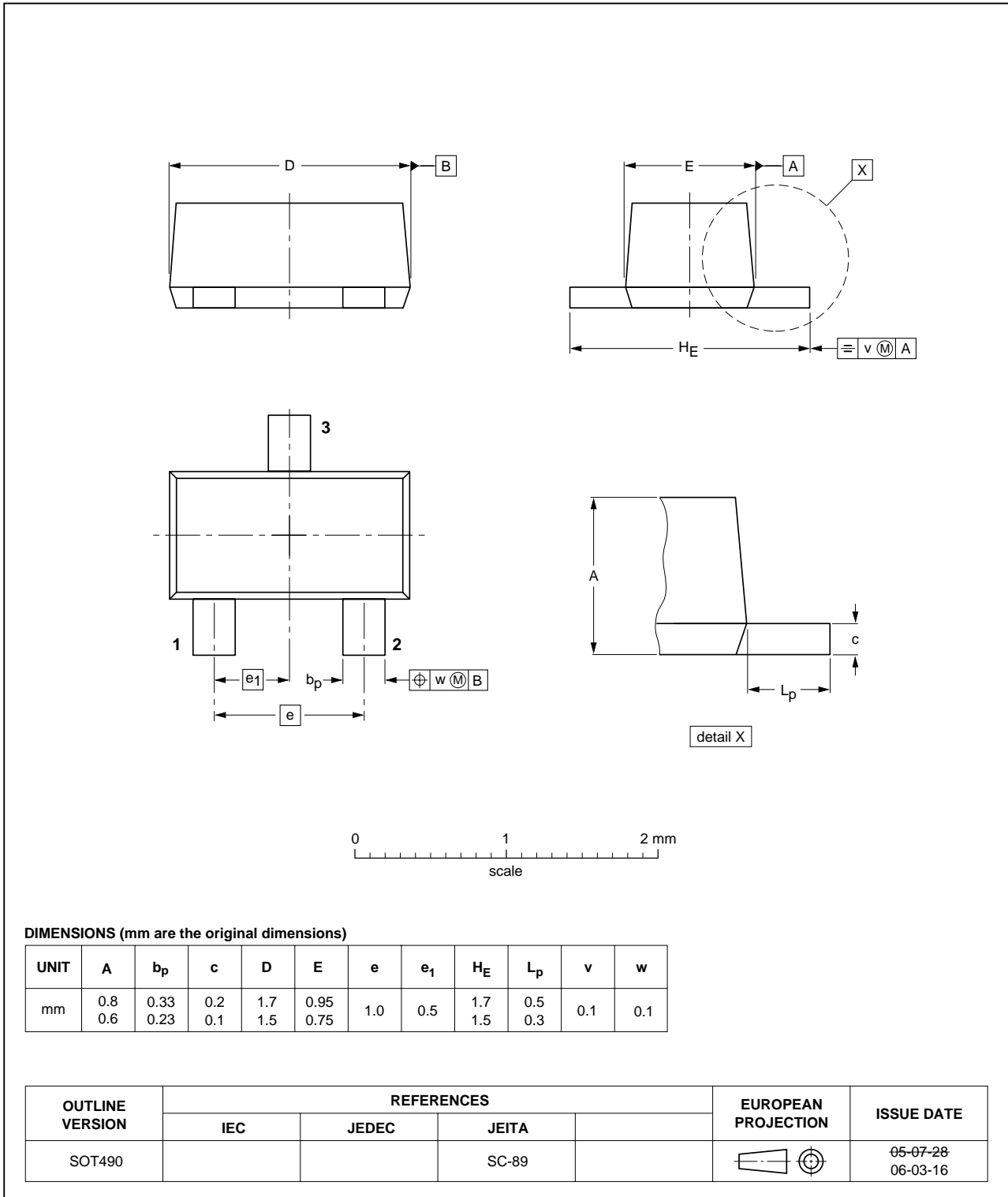
NPN resistor-equipped transistors;
R1 = 22 kΩ, R2 = open

PDTC124T series

PACKAGE OUTLINES

Plastic surface-mounted package; 3 leads

SOT490

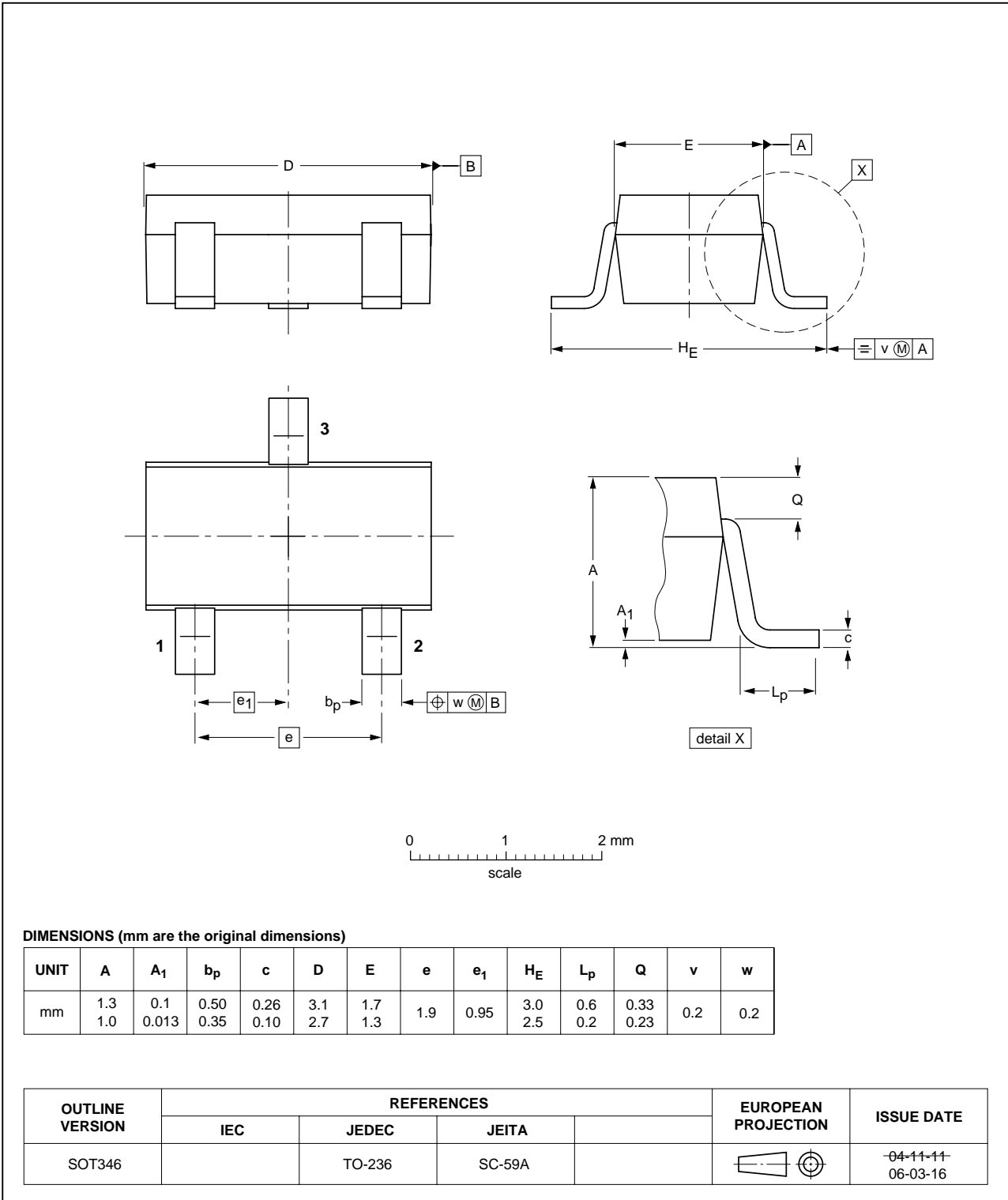


NPN resistor-equipped transistors;
R1 = 22 kΩ, R2 = open

PDTC124T series

Plastic surface-mounted package; 3 leads

SOT346

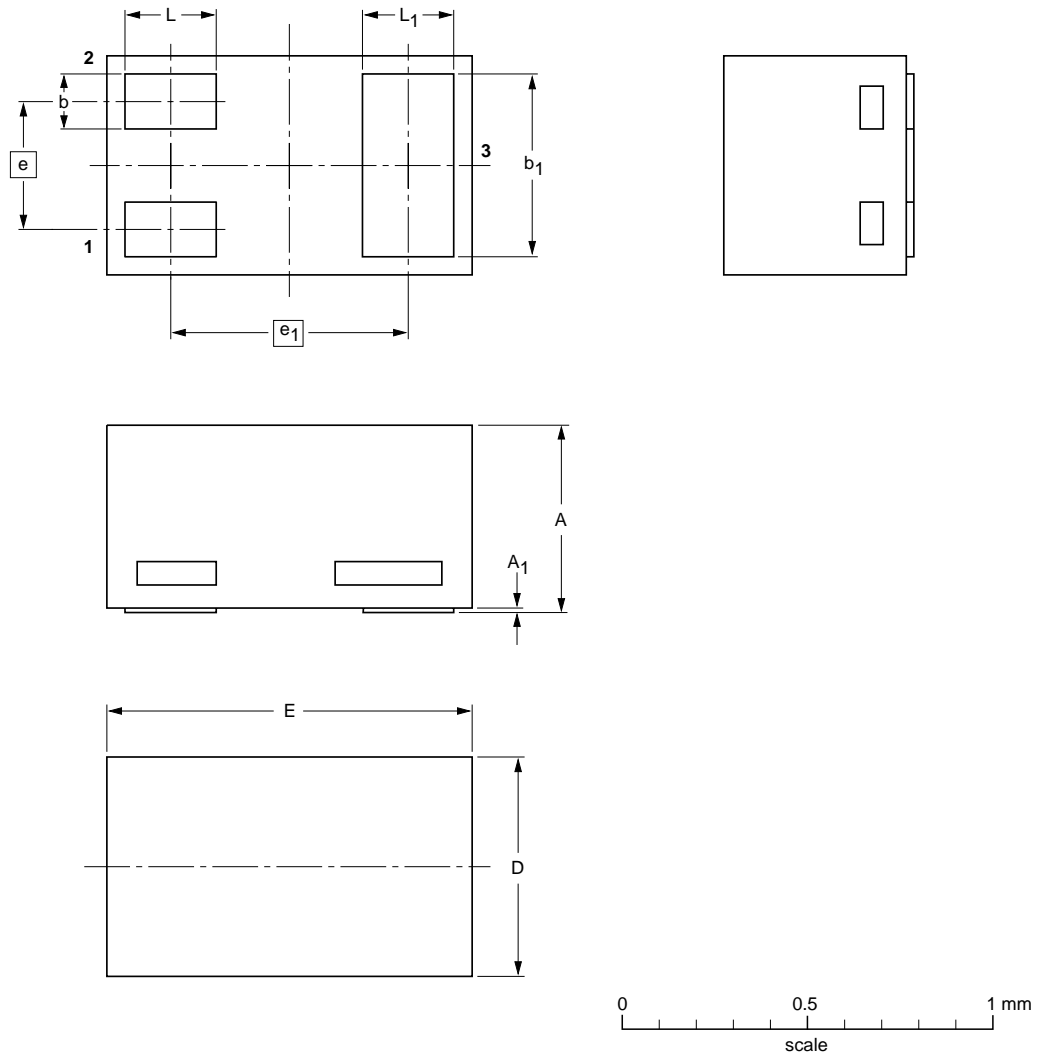


NPN resistor-equipped transistors;
R1 = 22 kΩ, R2 = open

PDTC124T series

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



DIMENSIONS (mm are the original dimensions)

UNIT	A ⁽¹⁾	A ₁ max.	b	b ₁	D	E	e	e ₁	L	L ₁
mm	0.50 0.46	0.03	0.20 0.12	0.55 0.47	0.62 0.55	1.02 0.95	0.35	0.65	0.30 0.22	0.30 0.22

Note

1. Including plating thickness

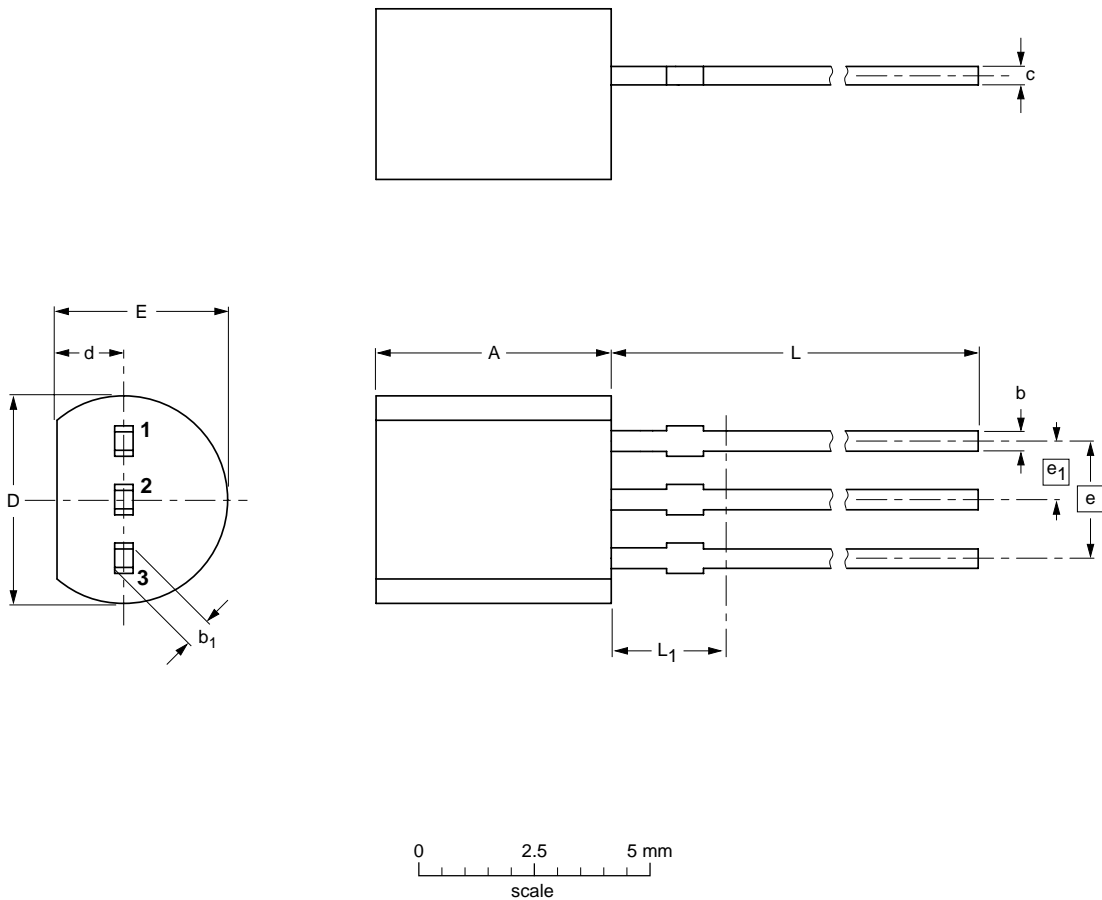
OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT883			SC-101		03-02-05 03-04-03

NPN resistor-equipped transistors;
R1 = 22 kΩ, R2 = open

PDTC124T series

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b ₁	c	D	d	E	e	e ₁	L	L ₁ ⁽¹⁾ max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

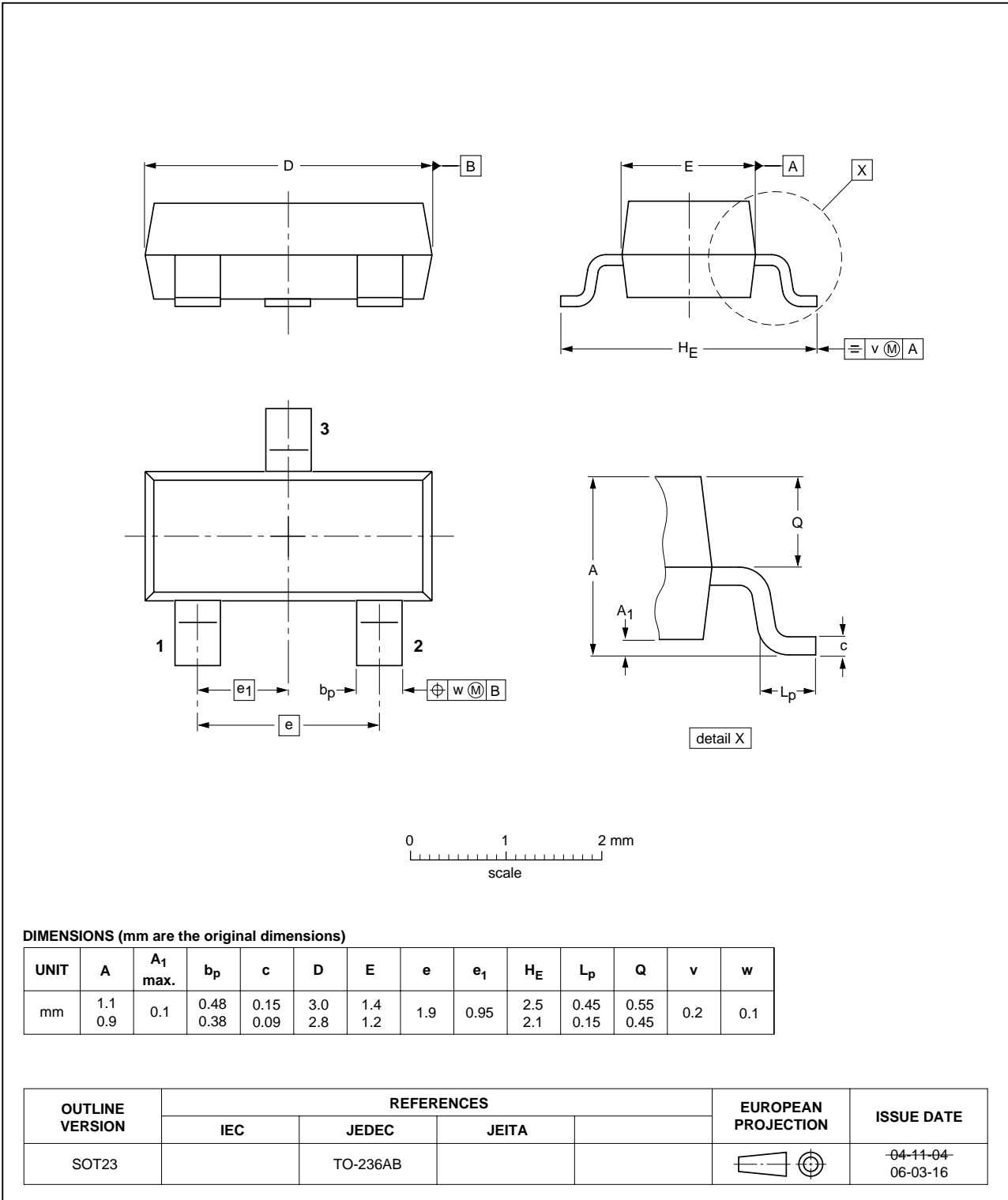
OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT54		TO-92	SC-43A		04-06-28 04-11-16

NPN resistor-equipped transistors;
R1 = 22 kΩ, R2 = open

PDTC124T series

Plastic surface-mounted package; 3 leads

SOT23

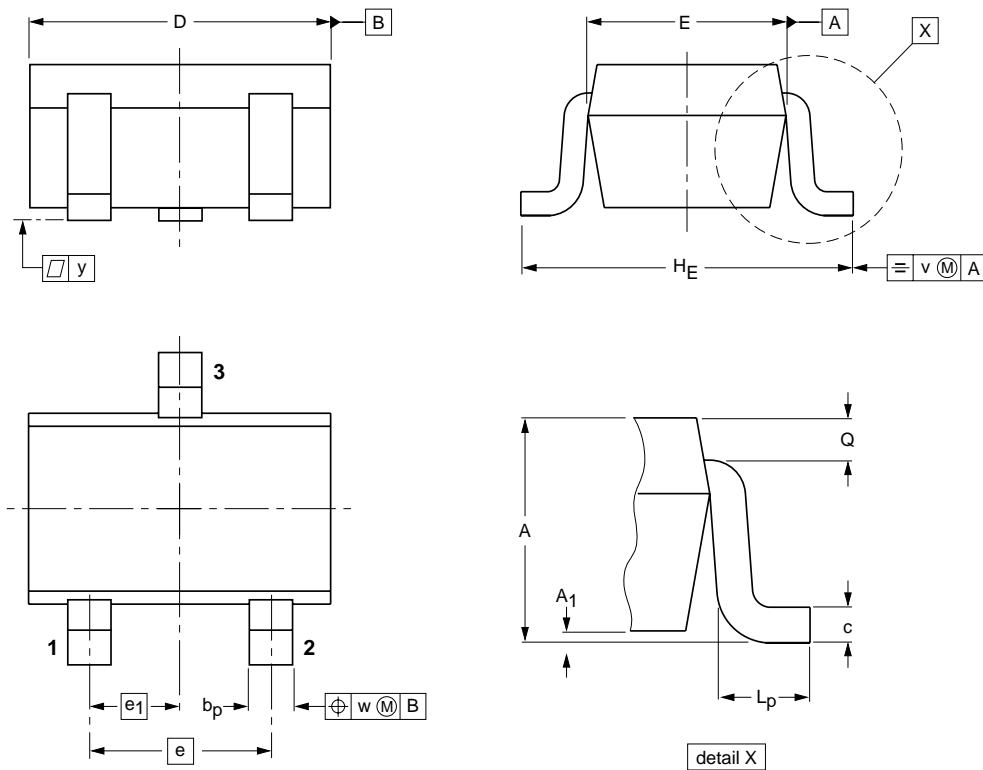


NPN resistor-equipped transistors;
R1 = 22 kΩ, R2 = open

PDTC124T series

Plastic surface-mounted package; 3 leads

SOT323



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

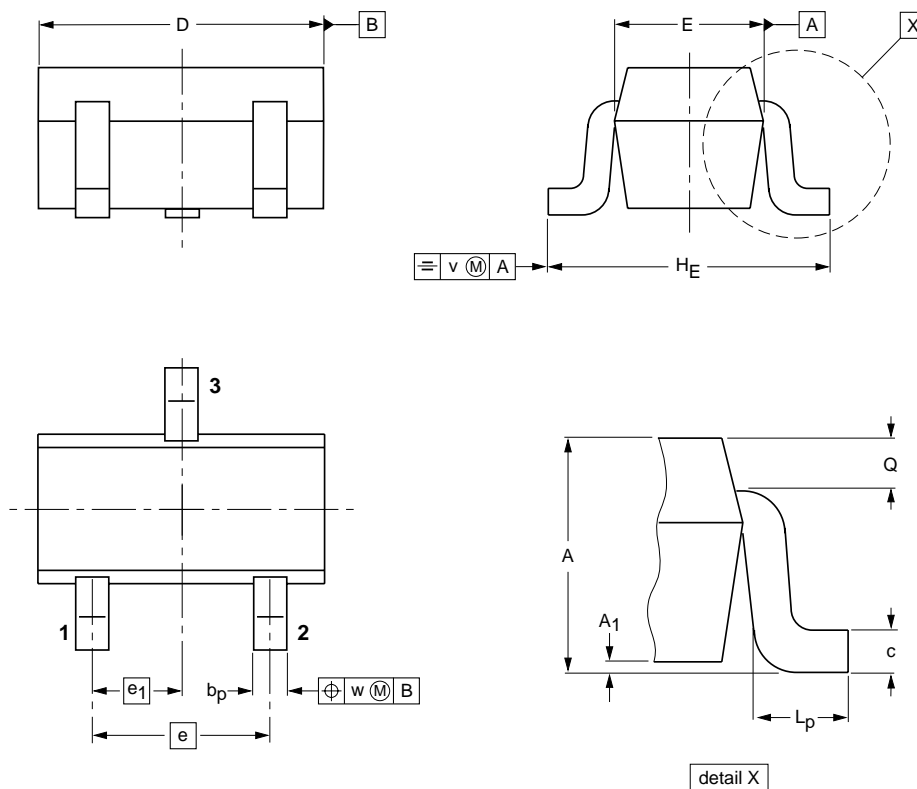
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT323			SC-70			04-11-04 06-03-16

NPN resistor-equipped transistors;
R1 = 22 kΩ, R2 = open

PDTC124T series

Plastic surface-mounted package; 3 leads

SOT416



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	bp	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT416			SC-75		04-11-04 06-03-16

NPN resistor-equipped transistors;
R1 = 22 k Ω , R2 = open

PDTC124T series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

1. Please consult the most recently issued document before initiating or completing a design.
2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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